DISCRETE SEMICONDUCTORS

DATA SHEET

BYW29EX series Rectifier diodes ultrafast, rugged

Product specification

September 2018



Rectifier diodes ultrafast, rugged

BYW29EX series

GENERAL DESCRIPTION

QUICK REFERENCE DATA

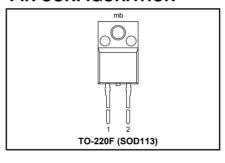
Glass passivated epitaxial rectifier diodes in a full pack plastic envelope, featuring low forward voltage drop, ultra-fast recovery times, soft recovery characteristic and guaranteed reverse surge and ESD capability. They are intended for use in switched mode power supplies and high frequency circuits in general where low conduction and switching losses are essential.

SYMBOL	PARAMETER	MAX.	MAX.	UNIT
V _{RRM}	BYW29EX- Repetitive peak reverse voltage Forward voltage	150 150 0.895	200 200 0.895	
I _{F(AV)} t _{rr} I _{RRM}	Forward current Reverse recovery time Repetitive peak reverse current	8 25 0.2	8 25 0.2	A ns A

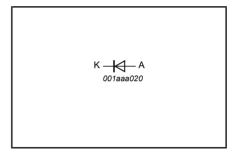
PINNING - SOD113

DESCRIPTION		
e		
d		

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V _{RRM} V _{RWM} V _R	Repetitive peak reverse voltage Crest working reverse voltage Continuous reverse voltage		1 1 1	-150 150 150 150	-200 200 200 200	\ \ \ \
I _{F(AV)}	Average forward current ¹	square wave; δ = 0.5; $T_{hs} \le 106 ^{\circ}\text{C}$ sinusoidal; a = 1.57;	-		8	A
	RMS forward current	T _{hs} ≤ 109 °C	-		.3 I.3	A A
I _{F(RMS)}		$t = 25 \mu s; \delta = 0.5;$ $T_{hs} \le 106 ^{\circ}C$	-		6	Ä
I _{FSM}	Non-repetitive peak forward current	t = 10 ms t = 8.3 ms sinusoidal; with reapplied	-		80 88	A A
I ² t I _{RRM} I _{RSM}	l ² t for fusing Repetitive peak reverse current Non-repetitive peak reverse	$egin{array}{l} V_{\text{RWM}(\text{max})} \ t = 10 \ \text{ms} \ t_{\text{p}} = 2 \ \mu \text{s}; \ \delta = 0.001 \ t_{\text{p}} = 100 \ \mu \text{s} \ \end{array}$	- - -	0	.2 .2 .2	A ² s A A
T _{stg}	current Storage temperature Operating junction temperature		-40 -		50 50	.C

¹ Neglecting switching and reverse current losses

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ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _C	Electrostatic discharge capacitor voltage	Human body model; C = 250 pF; R = 1.5 kΩ	-	8	kV

ISOLATION LIMITING VALUE & CHARACTERISTIC

T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from both terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65%; clean and dustfree	-		2500	٧
C _{isol}	Capacitance from both terminals to external heatsink	f = 1 MHz	-	10	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th j-hs}$ $R_{th j-a}$	heatsink	with heatsink compound without heatsink compound in free air		- - 55	5.5 7.2 -	K/W K/W K/W

STATIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage	$I_F = 8 \text{ A}; T_i = 150^{\circ}\text{C}$	-	0.80	0.895	V
	_	$I_F = 8 A$	-	0.92	1.05	V
		$I_{\rm F} = 20 \text{ A}$	-	1.1	1.3	V
l _R	Reverse current	$V_R = V_{RWM}$; $T_i = 100 ^{\circ}C$	-	0.2	0.6	mA
		$V_R = V_{RWM}$	-	2	10	μΑ

DYNAMIC CHARACTERISTICS

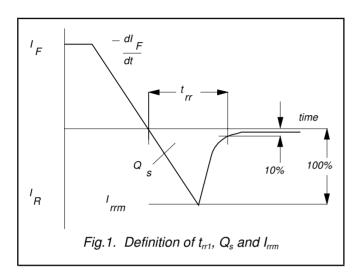
T_i = 25 °C unless otherwise stated

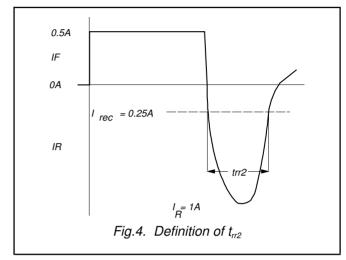
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Q_s	Reverse recovery charge	$I_F = 2 \text{ A}; V_R \ge 30 \text{ V}; -dI_F/dt = 20 \text{ A}/\mu\text{s}$	-	4	11	nC
t _{rr1}	Reverse recovery time	$I_{\rm F} = 1 \text{A}; V_{\rm R} \ge 30 \text{V};$	-	20	25	ns
t _{rr2} V _{fr}	Reverse recovery time	$ -dI_F/dt = 100 \text{ A/}\mu\text{s}$ $ I_F = 0.5 \text{ A to } I_R = 1 \text{ A; } I_{rec} = 0.25 \text{ A}$	-	15	20	ns
V_{fr}	Forward recovery voltage	$I_F = 1 \text{ A}; dI_F/dt = 10 \text{ A/}\mu\text{s}$	-	1	-	V

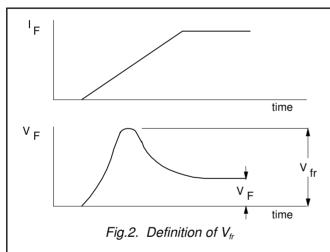
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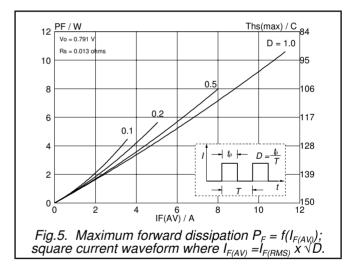
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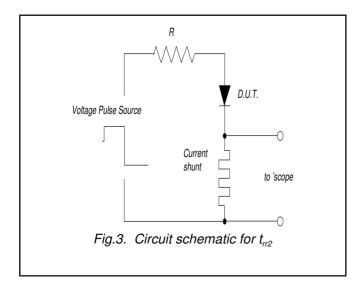
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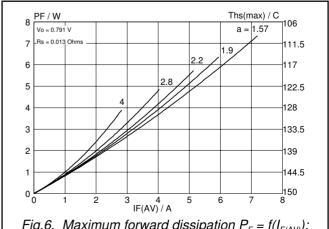
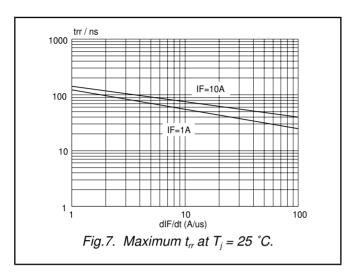


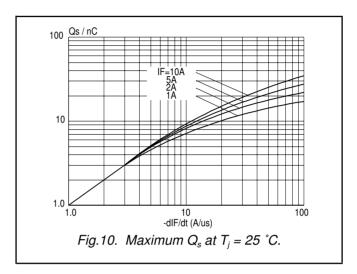
Fig.6. Maximum forward dissipation $P_F = f(I_{F(AV)})$; sinusoidal current waveform where a = form factor $= I_{F(RMS)} / I_{F(AV)}$.

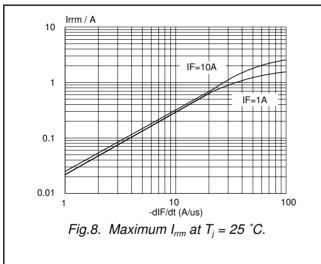
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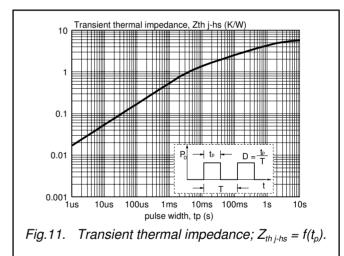
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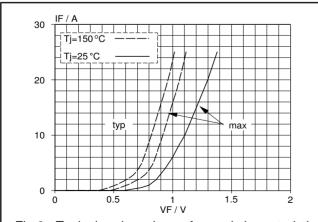


Fig.9. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

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15-08-28

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MECHANICAL DATA

SOD113

Plastic single- ended package; isolated heatsink mounted; 1 mounting hole; 2- lead TO- 220 'full pack' SOD113 T(4) H_{E} i(3) k⁽³⁾ Q |**←**||e||**→** 10 mm scale Dimensions (mm are the original dimensions) H_{E} j(3) $L_1^{(1)}$ T⁽⁴⁾ $z^{(2)}$ D Е Р Q Unit b_1 1 h C е w m q max max 10.3 14.4 max 4.6 2.9 0.9 1.1 0.7 15.8 2.7 0.6 3.3 6.5 3.2 2.6 nom 5.08 19.0 0.5 2.6 2.55 0.4 8.0 4.0 2.5 0.7 0.9 0.4 15.2 9.7 0.4 13.5 2.8 6.3 3.0 2.3 Notes 1. Terminals are uncontrolled within zone L1. 2. z is depth of T. 3. Dot lines area designs may vary. 4. Eject pin mark is for reference only sod113_po References European Issue date version projection JEITA IEC **JEDEC**

2-lead TO-220F

Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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